

ECE 3318

Applied Electricity and Magnetism

Spring 2023

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Dept. of ECE



Notes 27
DC Currents

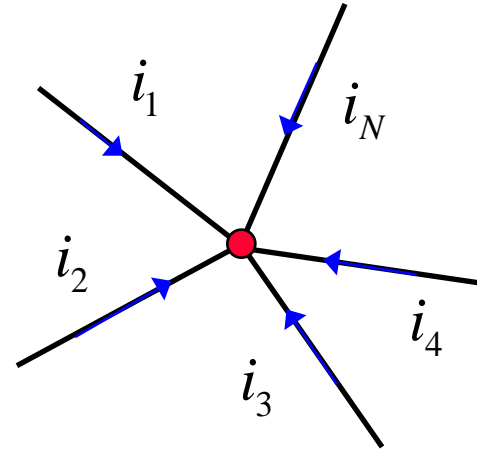
KCL Law

Wires meet at a “node”

$$\sum_{n=1}^N i_n = 0$$

or

$$i_{in}^{tot} = 0$$



Note:

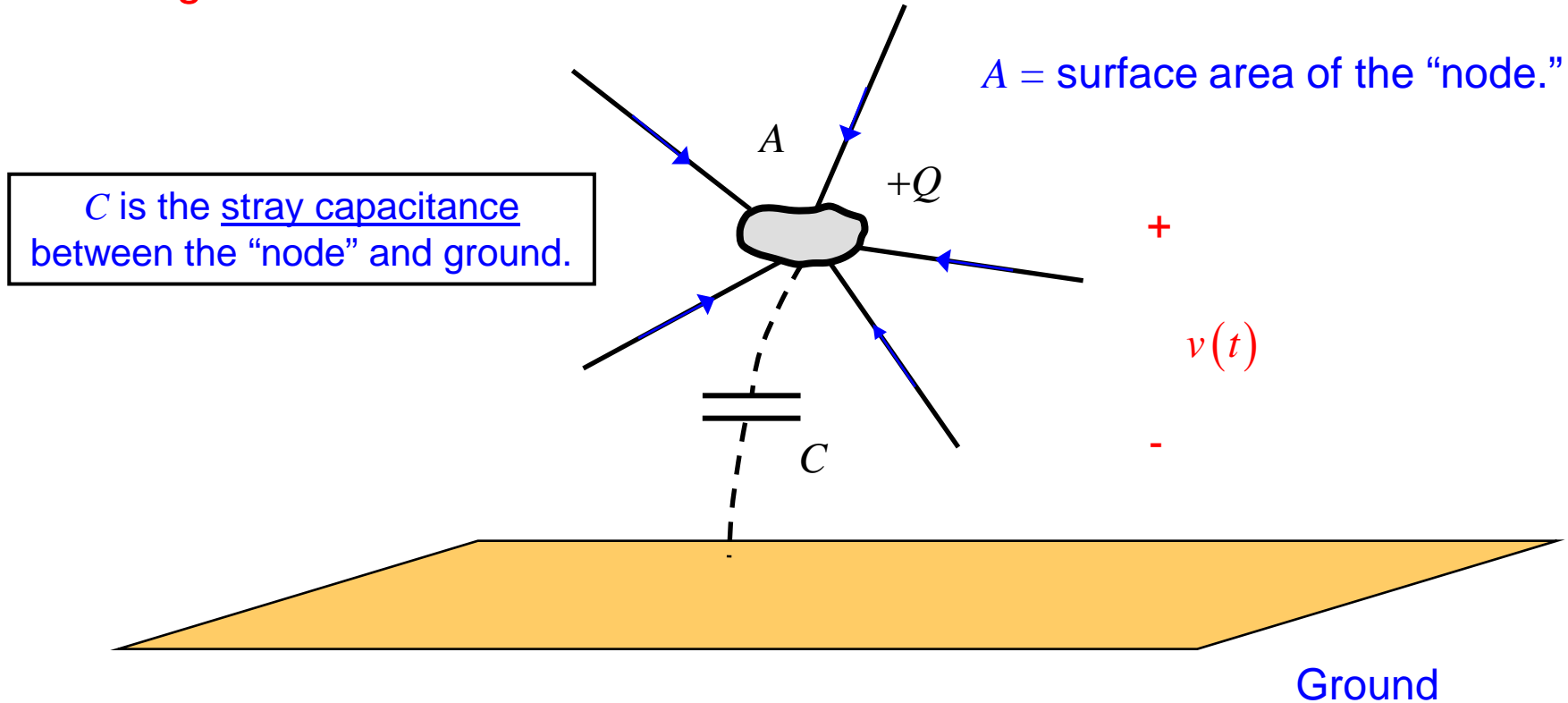
The “node” can be a single point or a larger region.

Or we can say $i_{out}^{tot} = 0$

A proof of the KCL law is given next.

KCL Law (cont.)

A single node is considered.

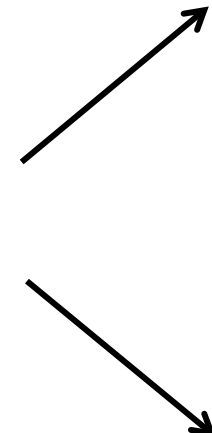


The node forms the top (anode) plate of a *stray capacitor*.

$$i_{in}^{tot} = C \frac{dv}{dt}$$


KCL Law (cont.)

Two cases for which the KCL law is valid:

$$i_{in}^{tot} = C \frac{dv}{dt}$$



1) In “steady state” (no time change)

$$\frac{dv}{dt} = 0$$


$$i_{in}^{tot} = 0$$

2) As area of node $A \rightarrow 0$

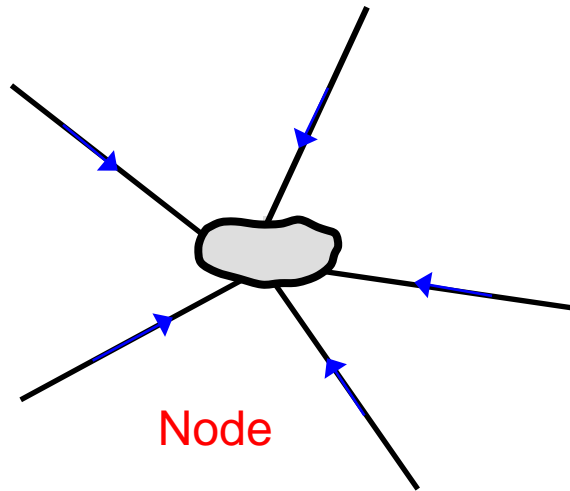
$$A \rightarrow 0 \Rightarrow C \rightarrow 0$$


$$i_{in}^{tot} = 0$$

KCL Law (cont.)

In general, the KCL law will be accurate if the size of the “node” is small compared with the wavelength λ_0 .

Currents enter a node at some frequency f .



f	λ_0
60 Hz	5000 [km]
1 kHz	300 [km]
1 MHz	300 [m]
1 GHz	30 [cm]

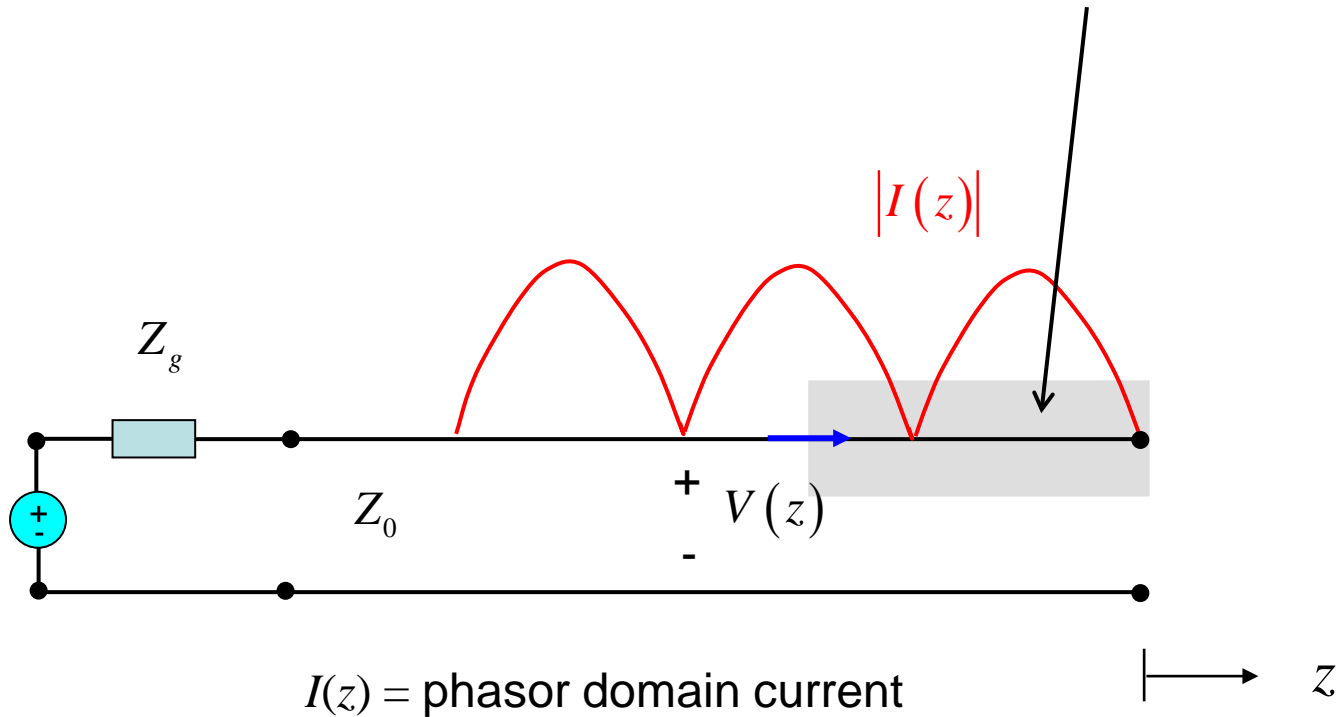
$$\lambda_0 = \frac{c}{f} = \frac{2.99792458 \times 10^8}{f}$$

KCL Law (cont.)

Example where the KCL is not valid

Open-circuited transmission line (ECE 3317)

Current enters this shaded region (“node”) but does not leave.



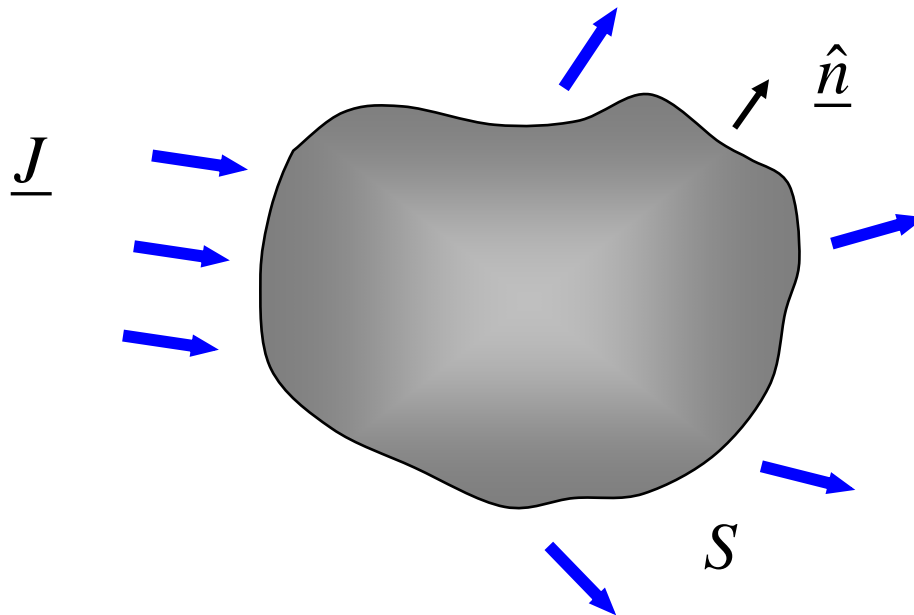
KCL Law (cont.)

General volume (3D) form of KCL equation:

$$i_{out} = \oint_S \underline{J} \cdot \underline{\hat{n}} dS = 0$$

(valid for D.C. currents)

The total current flowing out (or in) must be zero: whatever flows in must flow out.



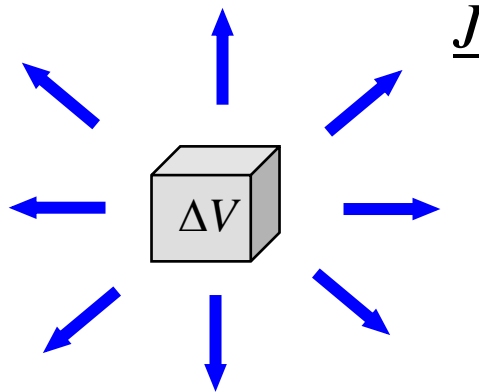
KCL Law (Differential Form)

To obtain the *differential form* of the KCL law for static (D.C.) currents, start with the definition of divergence:

$$\nabla \cdot \underline{J} \equiv \lim_{\Delta V \rightarrow 0} \frac{1}{\Delta V} \oint_{\Delta S} \underline{J} \cdot \hat{n} dS$$

For the right-hand side:

$$\oint_{\Delta S} \underline{J} \cdot \hat{n} dS = i_{out} = 0$$



Hence

$$\nabla \cdot \underline{J} = 0$$

(valid for D.C. currents)

Important Current Formulas

These two formulas hold in general (not only at DC):

Ohm's Law

$$\underline{J} = \sigma \underline{E}$$

(This is an experimental law that was introduced earlier in the semester.)

Charge-Current Formula

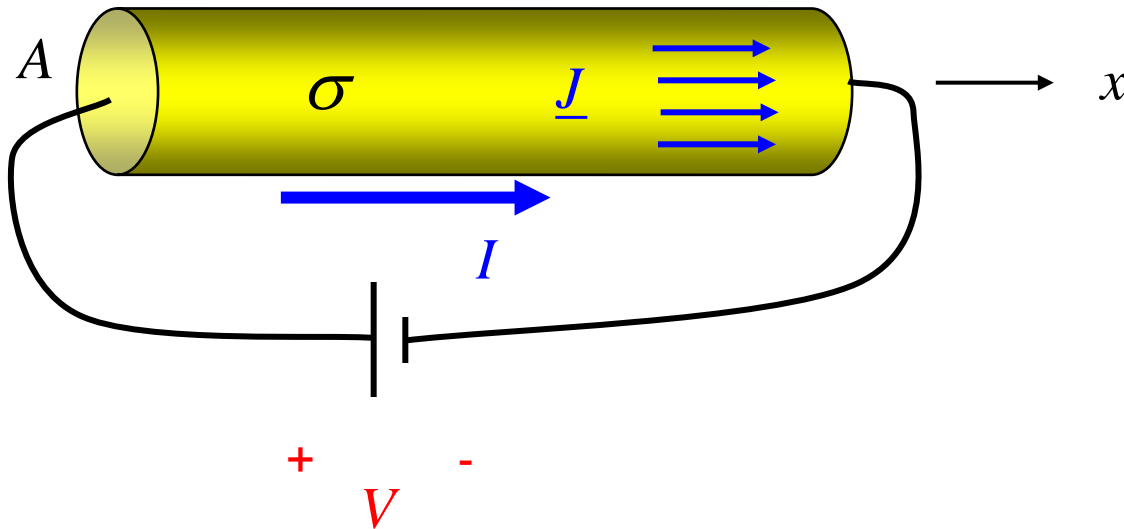
$$\underline{J} = \rho_v \underline{v}$$

(This was derived earlier in the semester.)

Resistor Formula

A long narrow resistor: $\underline{E} \approx \hat{x} E_{x0}$

L



Note:
The electric field is constant (does not change with x) since the current must be uniform (KCL law).

$$E_{x0} = \frac{V}{L}$$

$$J_x = \sigma E_{x0} = \sigma \left(\frac{V}{L} \right)$$

$$I = J_x A = \sigma \left(\frac{V}{L} \right) A$$

Solve for V from the last equation: $V = I \left(\frac{L}{\sigma A} \right)$

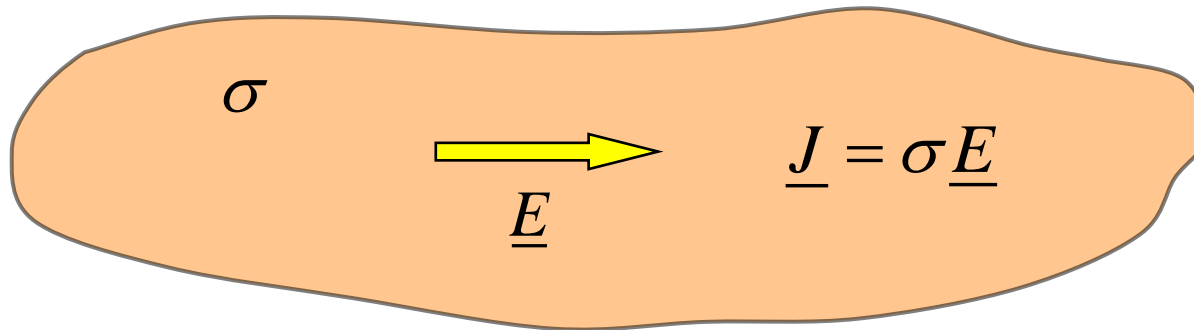
We also have that $R = \frac{V}{I}$

Hence we have

$$R = \left(\frac{L}{\sigma A} \right) [\Omega]$$

Joule's Law

(Please see Appendix A for a derivation.)



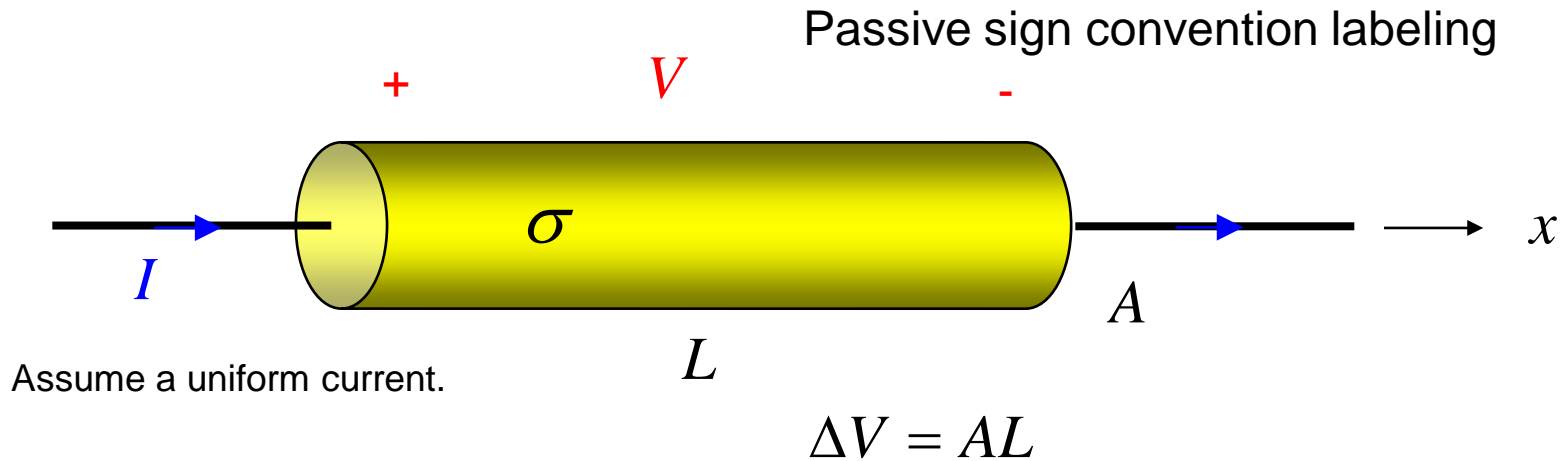
Conducting body

The power dissipated inside the body as heat is:

$$P_d = \int_V \underline{J} \cdot \underline{E} dV = \int_V \sigma |\underline{E}|^2 dV = \int_V \frac{|\underline{J}|^2}{\sigma} dV \quad [\text{W}]$$

Power Dissipation by Resistor

Resistor



$$\begin{aligned} P_d &= J_x E_x \Delta V \\ &= \left(\frac{I}{A} \right) \left(\frac{V}{L} \right) \Delta V \\ &= IV \end{aligned}$$

Hence

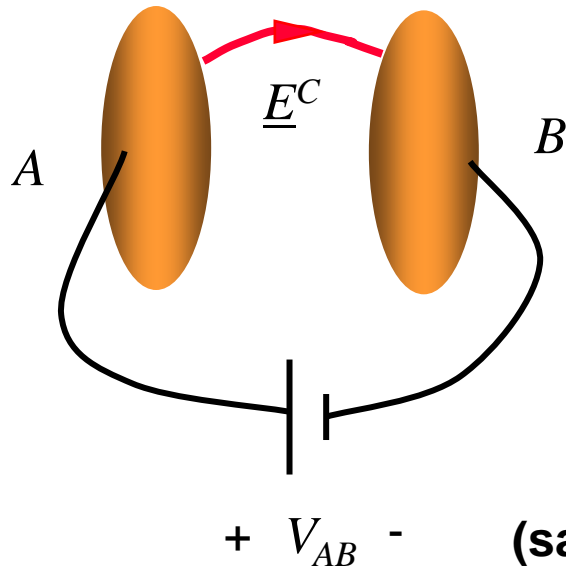
$$\begin{aligned} P_d &= VI \\ P_d &= RI^2 \end{aligned}$$

Note: The passive sign convention applies to the VI formula.

RC Analogy

Insulating material

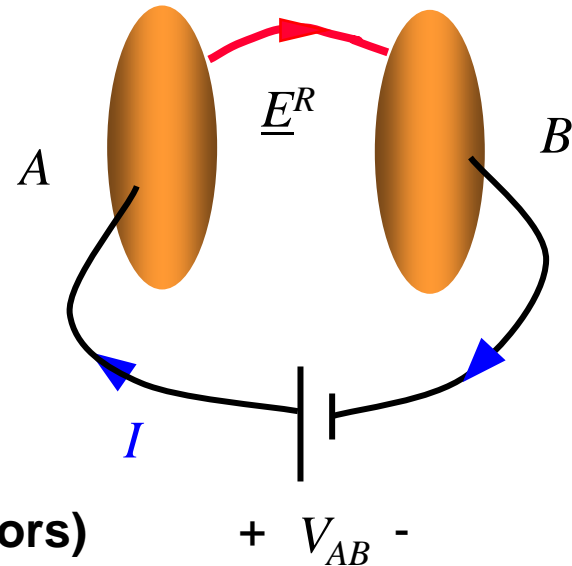
$$\varepsilon(\underline{r}) = F(\underline{r})$$



"C problem"

Conducting material

$$\sigma(\underline{r}) = F(\underline{r})$$



"R problem"

Goal:

Assuming we know how to solve the C problem (i.e., find C), can we solve the R problem (find R)?

RC Analogy

(Please see Appendix B for a derivation.)

Recipe for calculating resistance:

- 1) Calculate the capacitance of the corresponding C problem.
- 2) Replace ε everywhere with σ to obtain G .
- 3) Take the reciprocal to obtain R .

In symbolic form:

$$\varepsilon \rightarrow \sigma$$

$$C \rightarrow G$$

RC Formula

(Please see Appendix B for a derivation.)

This is a special case: A homogeneous medium of conductivity σ surrounds the two conductors (there is only one value of σ).

σ = conductivity in resistor problem

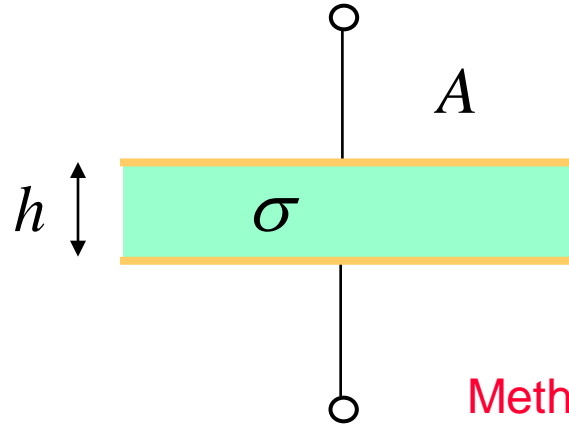
ε = permittivity in capacitor problem

The resistance R of the resistor problem is related to the capacitance C of the capacitor problem as follows:

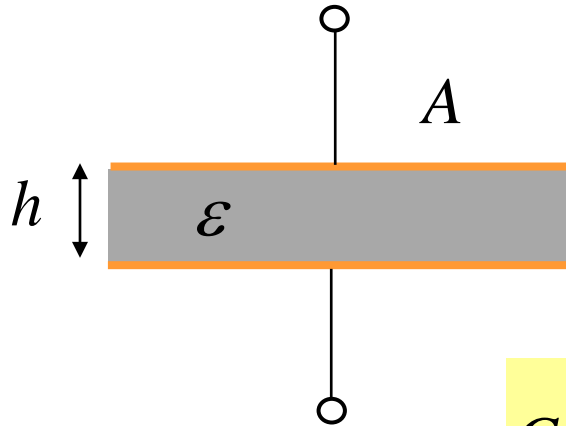
$$RC = \left(\frac{\varepsilon}{\sigma} \right)$$

Example

Find R



C problem:



$$C = \frac{\epsilon A}{h}$$

Method #1 (RC analogy or "recipe")

$$\epsilon \rightarrow \sigma$$

$$C \rightarrow G$$

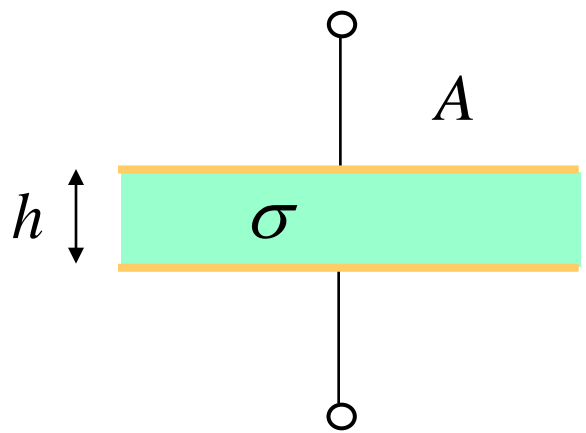
$$C = \frac{\epsilon A}{h} \rightarrow G = \frac{\sigma A}{h}$$

Hence

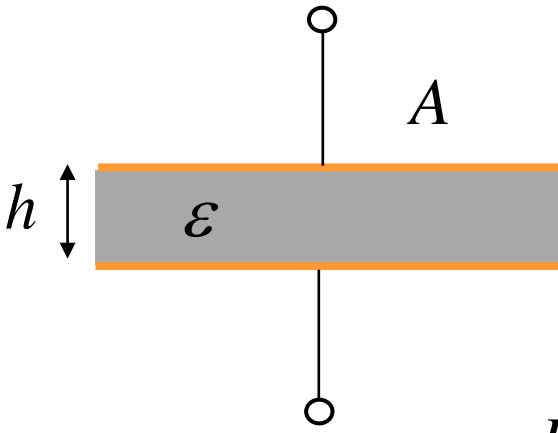
$$R = \frac{h}{\sigma A}$$

Example (cont.)

Find R



C problem:

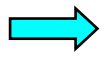


Method #2 (RC formula)

$$C = \frac{\epsilon A}{h}$$

$$RC = \left(\frac{\epsilon}{\sigma} \right)$$

$$R \left(\frac{\cancel{\epsilon A}}{h} \right) = \left(\frac{\cancel{\epsilon}}{\sigma} \right)$$

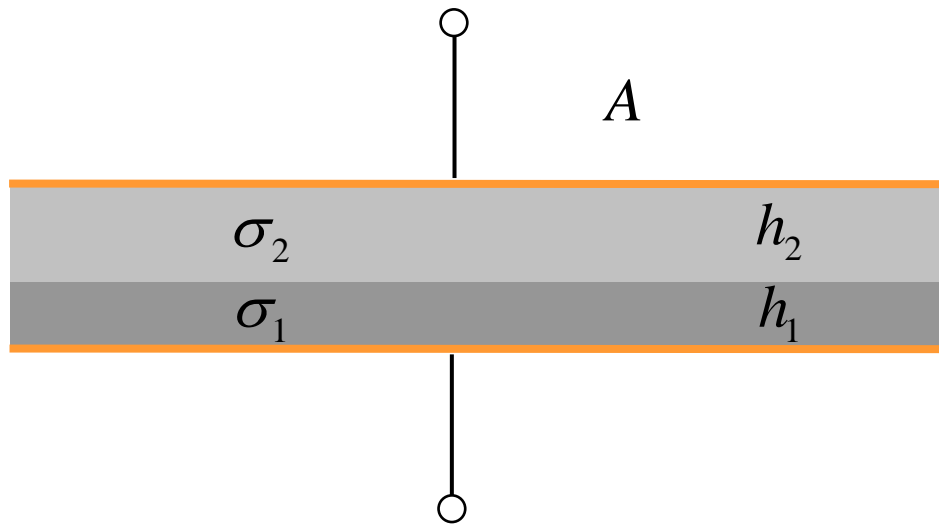


$$R = \frac{h}{\sigma A}$$

Note that the ϵ cancels out!

Example

Find the resistance

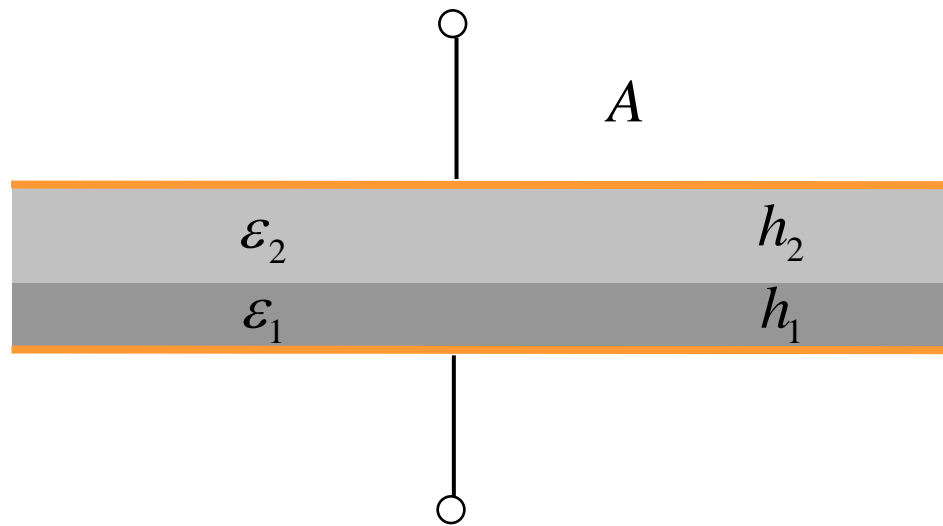


Note:

We cannot use the RC formula, since there is more than one region (not a single conductivity).

Example (cont.)

C problem:

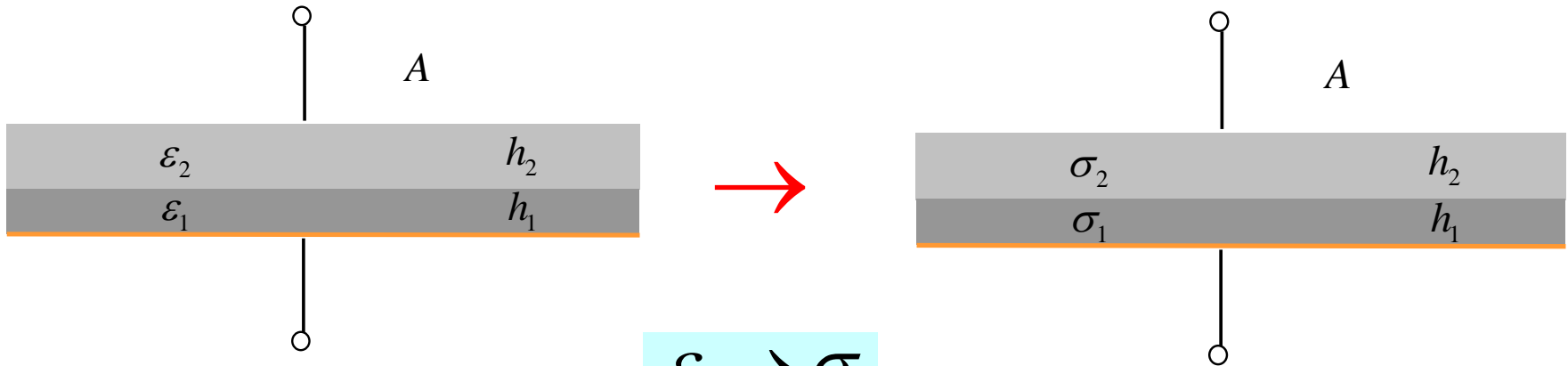


$$\frac{1}{C} = \frac{1}{C_1} + \frac{1}{C_2}$$

$$C_1 = \frac{\epsilon_1 A}{h_1}$$

$$C_2 = \frac{\epsilon_2 A}{h_2}$$

Example (cont.)



$$\begin{aligned} \epsilon &\rightarrow \sigma \\ C &\rightarrow G \end{aligned}$$

$$\frac{1}{C} = \frac{1}{C_1} + \frac{1}{C_2}$$



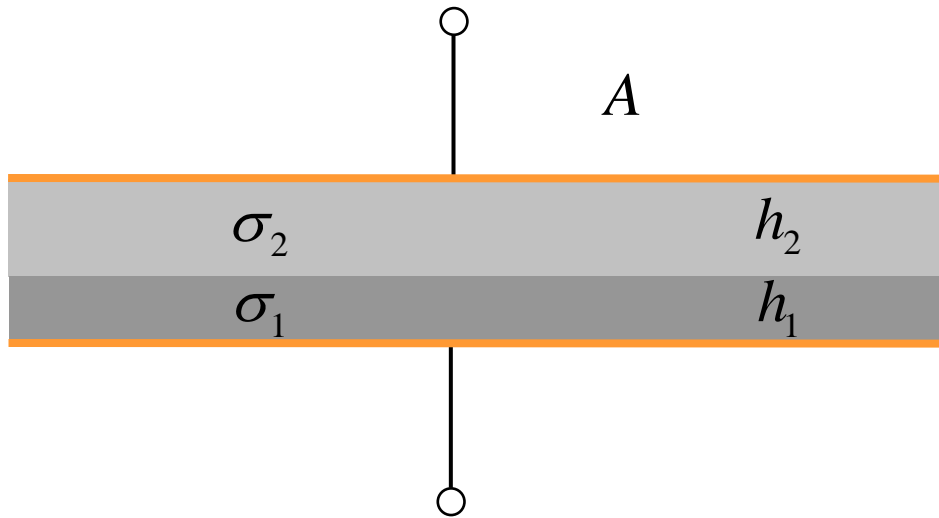
$$\frac{1}{G} = \frac{1}{G_1} + \frac{1}{G_2}$$

$$C_1 = \frac{\epsilon_1 A}{h_1} \quad C_2 = \frac{\epsilon_2 A}{h_2}$$



$$G_1 = \frac{\sigma_1 A}{h_1} \quad G_2 = \frac{\sigma_2 A}{h_2}$$

Example (cont.)



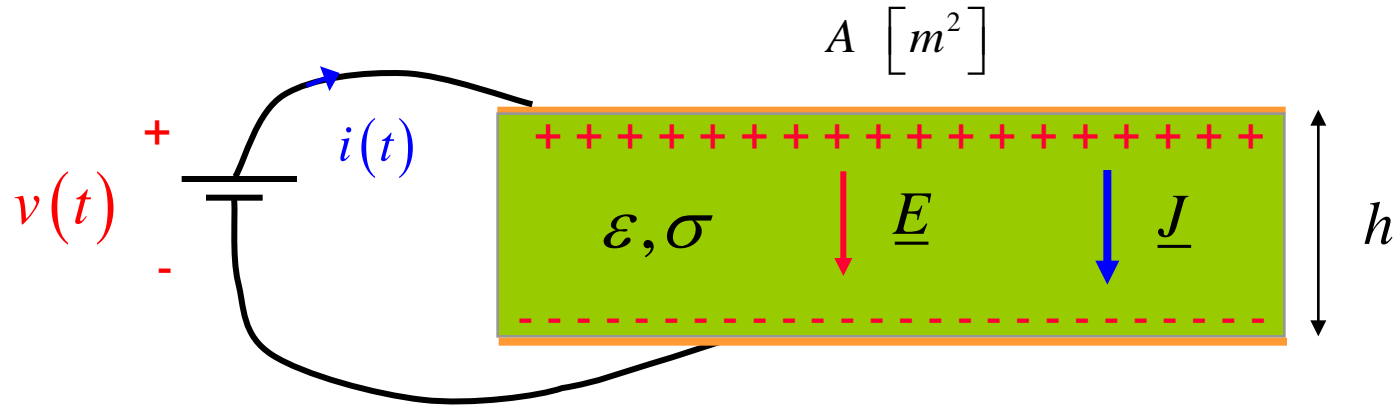
Hence, we have

$$R = R_1 + R_2$$

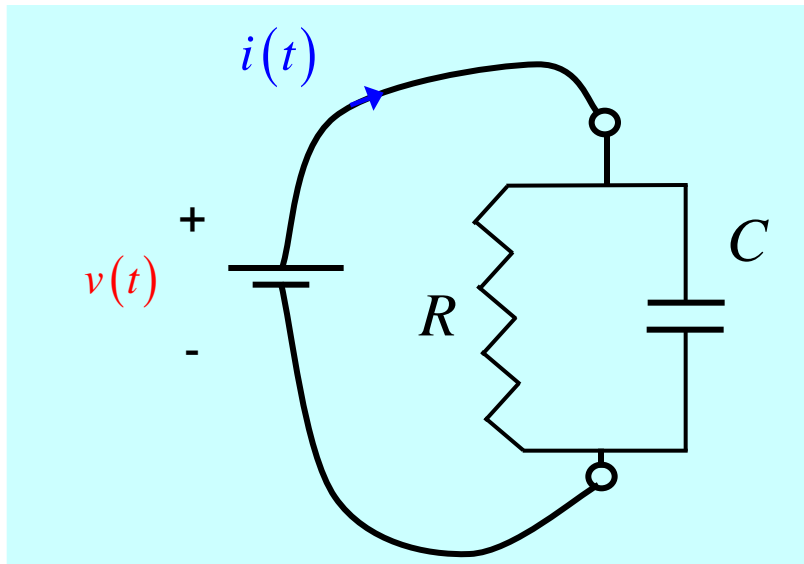
$$R_1 = \frac{h_1}{\sigma_1 A}$$

$$R_2 = \frac{h_2}{\sigma_2 A}$$

Lossy Capacitor



This is modeled by a parallel equivalent circuit
(The proof is in Appendix C.)



$$C = \frac{\epsilon A}{h}$$

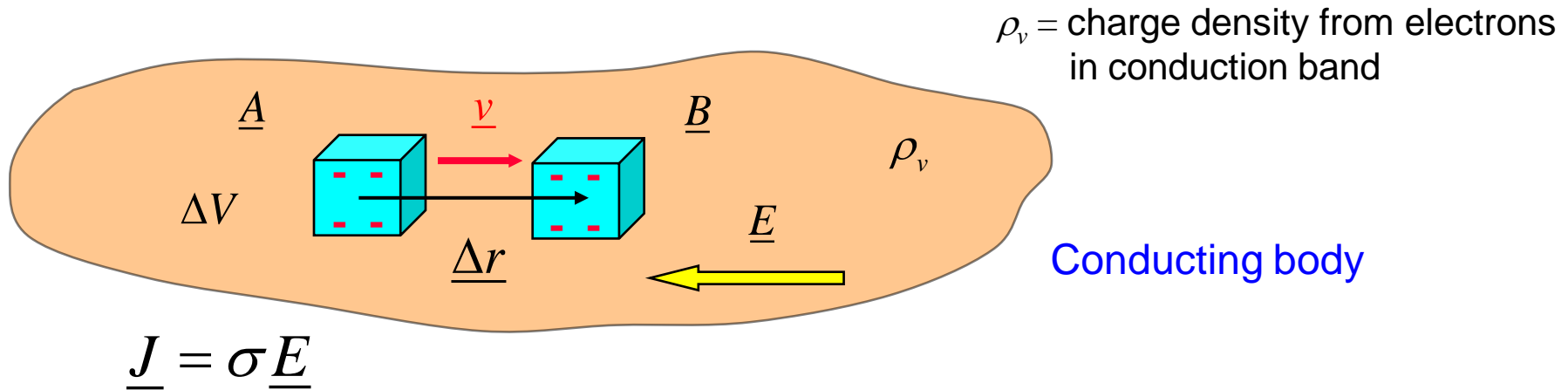
$$R = \frac{h}{\sigma A}$$

Note:
The time constant is
 $\tau = RC$

Appendix A

Derivation of Joule's Law

Joule's Law



$\Delta W =$ work (energy) given to a small volume of charge as it moves inside the conductor from point A to point B.

This goes to heat!

(There is no acceleration of charges in steady state, as this would cause current to change along the conductor, violating the KCL law.)

$$\begin{aligned} \Delta W &= \Delta Q V_{AB} \\ &\approx (\rho_v \Delta V) \int_A^B \underline{E} \cdot d\underline{r} \\ &\approx (\rho_v \Delta V) \underline{E} \cdot \underline{\Delta r} \\ &= \Delta V (\rho_v \underline{\Delta r}) \cdot \underline{E} = \Delta V \left(\rho_v \frac{\underline{\Delta r}}{\Delta t} \right) \cdot \underline{E} \Delta t \end{aligned}$$

Joule's Law (cont.)

$$\Delta W = \Delta V \left(\rho_v \frac{\Delta \underline{r}}{\Delta t} \right) \cdot \underline{E} \Delta t = \Delta V (\rho_v \underline{v}) \cdot \underline{E} \Delta t$$

$$\begin{aligned} \text{power / volume} &= \left(\frac{\Delta W}{\Delta t} \right) \left(\frac{1}{\Delta V} \right) = (\rho_v \underline{v}) \cdot \underline{E} \\ &= \underline{J} \cdot \underline{E} \end{aligned}$$

The total power dissipated is then

$$P_d = \int_V \underline{J} \cdot \underline{E} dV \quad [\text{W}]$$

We can also write

$$P_d = \int_V \sigma |\underline{E}|^2 dV = \int_V \frac{|\underline{J}|^2}{\sigma} dV \quad [\text{W}]$$

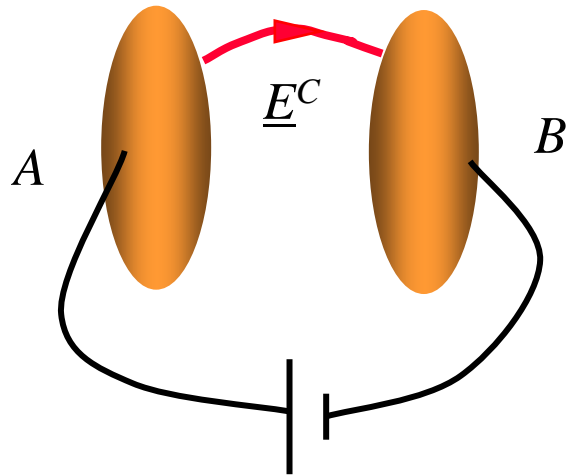
Appendix B

Derivation of RC Analogy and RC Formula

RC Analogy

Insulating material

$$\varepsilon(\underline{r}) = F(\underline{r})$$



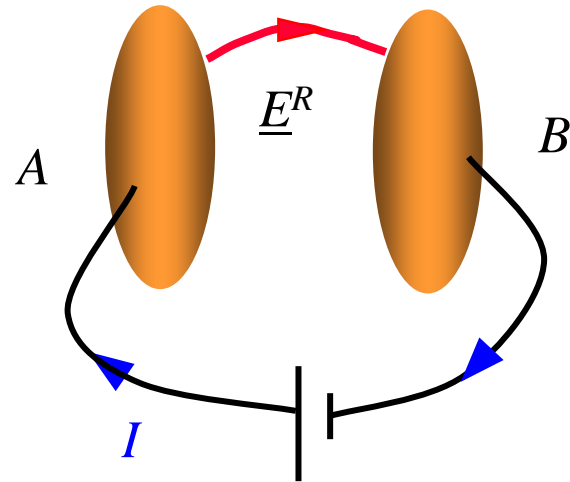
+ V_{AB} -

(same conductors)

“C problem”

Conducting material

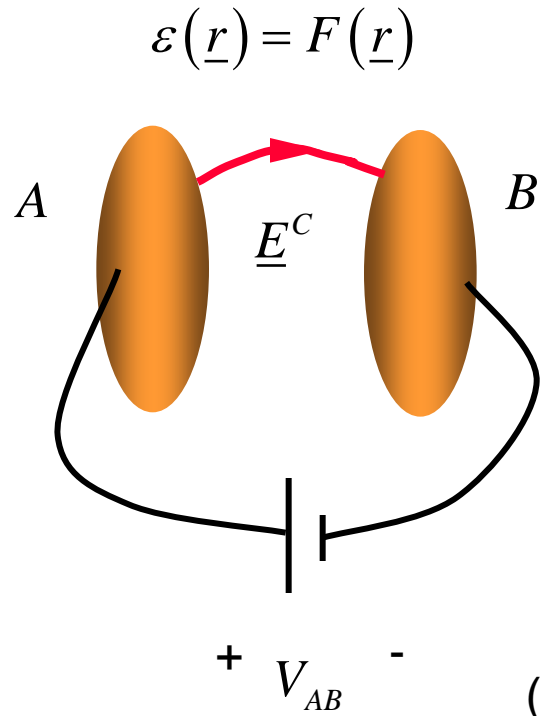
$$\sigma(\underline{r}) = F(\underline{r})$$



+ V_{AB} -

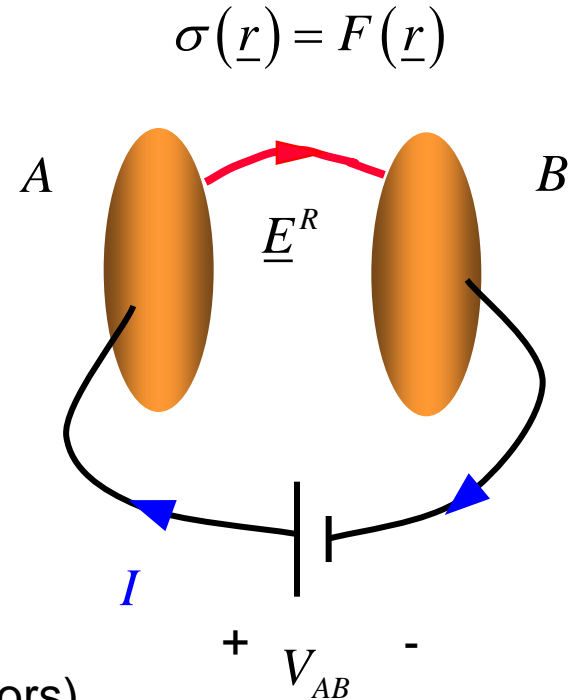
“R problem”

RC Analogy (cont.)



“C problem”

(same conductors)



“R problem”

Theorem: $\underline{E}^C = \underline{E}^R$ (same field in both problems)

RC Analogy (cont.)

Proof of “theorem”

“C problem”

$$\nabla \cdot \underline{D} = 0$$

$$\Rightarrow \nabla \cdot (\varepsilon \underline{E}) = 0$$

“R problem”

$$\nabla \cdot \underline{J} = 0$$

$$\Rightarrow \nabla \cdot (\sigma \underline{E}) = 0$$

- Same differential equation since $\varepsilon(\underline{r}) = \sigma(\underline{r})$
- Same B. C. since the same voltage is applied

$$\text{Hence, } \underline{E}^C = \underline{E}^R$$

(The two electric fields must be the same function from the uniqueness of the solution to the differential equation.)

RC Analogy (cont.)

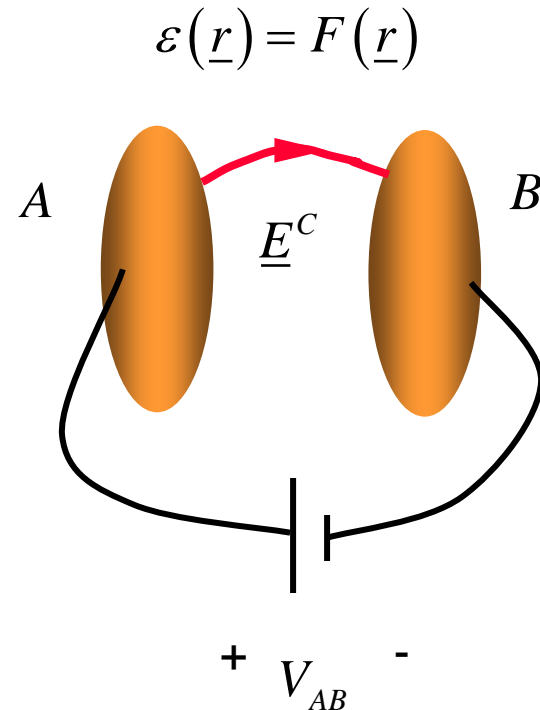
$$C = \frac{Q}{V} = \frac{Q_A}{V_{AB}}$$

$$= \frac{\oint_{S_A} \rho_s dS}{\int_A^B \underline{E} \cdot \underline{dr}}$$

Use $\rho_s = \underline{D} \cdot \underline{\hat{n}} = \varepsilon \underline{E} \cdot \underline{\hat{n}}$

Hence

$$C = \frac{\oint_{S_A} \varepsilon \underline{E} \cdot \underline{\hat{n}} dS}{\int_A^B \underline{E} \cdot \underline{dr}}$$



“C Problem”

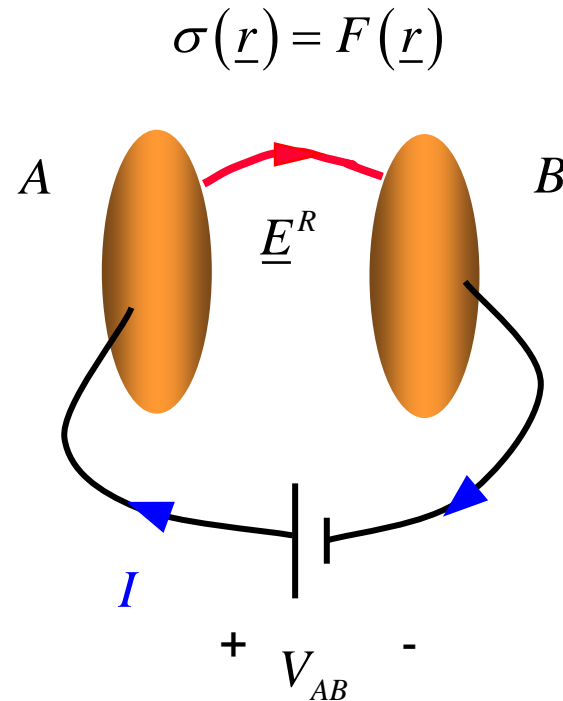
RC Analogy (cont.)

$$R = \frac{V}{I} = \frac{V_{AB}}{I_A}$$
$$= \frac{\int_A^B \underline{E} \cdot \underline{dr}}{\oint_{S_A} \underline{J} \cdot \underline{\hat{n}} dS}$$

Use $\underline{J} = \sigma \underline{E}$

Hence

$$R = \frac{\int_A^B \underline{E} \cdot \underline{dr}}{\oint_{S_A} \sigma \underline{E} \cdot \underline{\hat{n}} dS}$$



“R Problem”

RC Analogy (cont.)

Compare:

$$C = \frac{\oint_{S_A} \epsilon \underline{E} \cdot \underline{\hat{n}} \, dS}{\int_A^B \underline{E} \cdot \underline{dr}} \qquad G = \frac{1}{R} = \frac{\oint_{S_A} \sigma \underline{E} \cdot \underline{\hat{n}} \, dS}{\int_A^B \underline{E} \cdot \underline{dr}}$$

Recall that $\sigma(\underline{r}) = \epsilon(\underline{r}) = F(\underline{r})$

Hence $C = G$

RC Formula

This is a special case: A homogeneous medium of conductivity σ surrounds the two conductors (there is only one value of σ).

$$C = \varepsilon \frac{\oint_{S_A} \underline{E} \cdot \underline{\hat{n}} dS}{\int_A^B \underline{E} \cdot \underline{dr}} \qquad G = \sigma \frac{\oint_{S_A} \underline{E} \cdot \underline{\hat{n}} dS}{\int_A^B \underline{E} \cdot \underline{dr}}$$

Hence,

$$G = C \left(\frac{\sigma}{\varepsilon} \right) \quad \text{or}$$

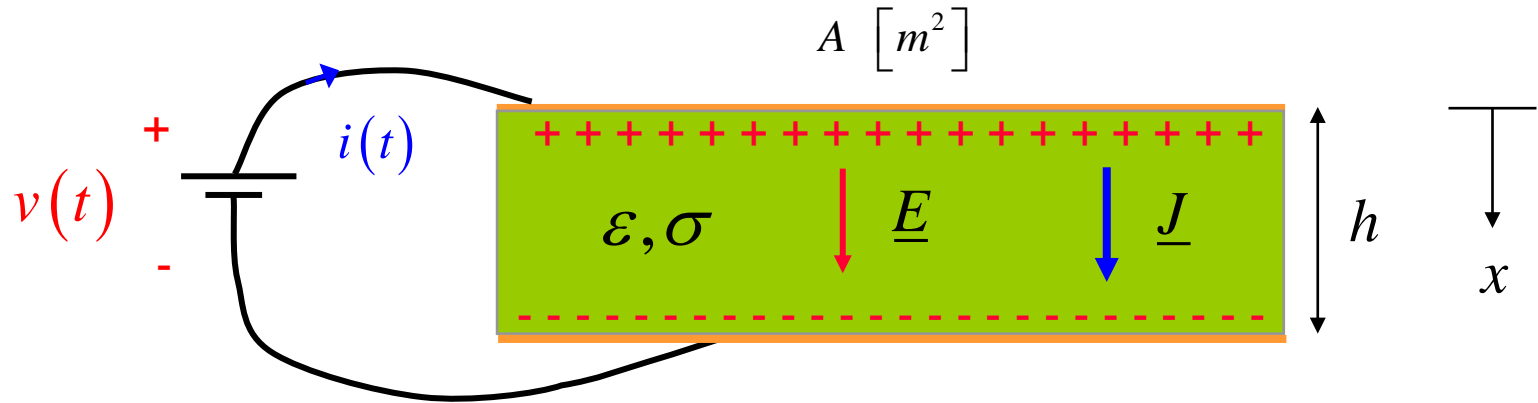
$$RC = \left(\frac{\varepsilon}{\sigma} \right)$$

Appendix C

Equivalent Circuit for a Lossy Capacitor

Lossy Capacitor

Derivation of equivalent circuit



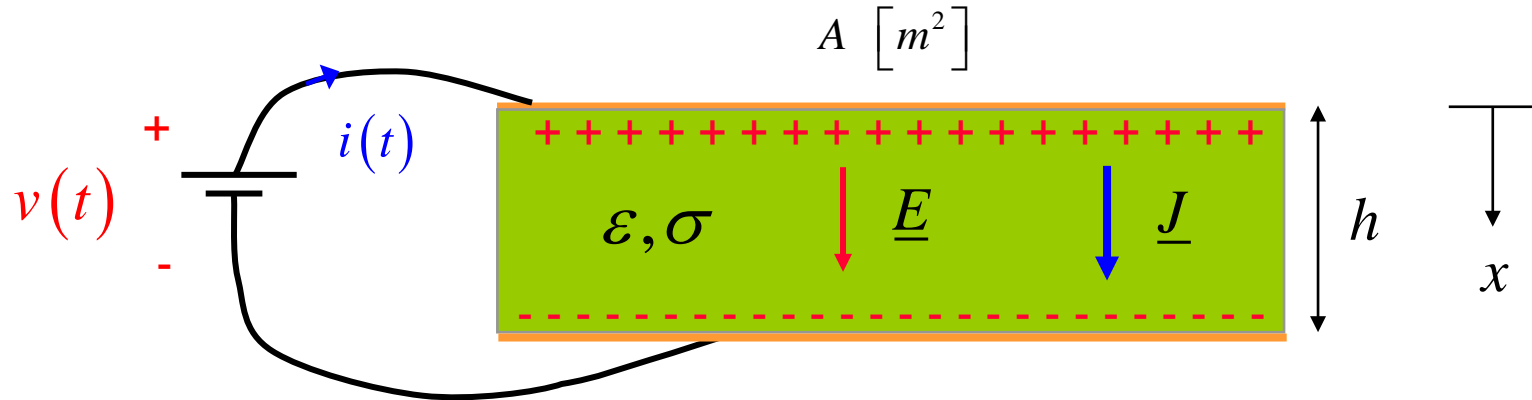
Total (net) current entering top (A) plate:

$$i_{in}^A(t) = i(t) - J_x A = \frac{dQ}{dt}$$

Therefore,

$$i(t) = J_x A + \frac{dQ}{dt}$$

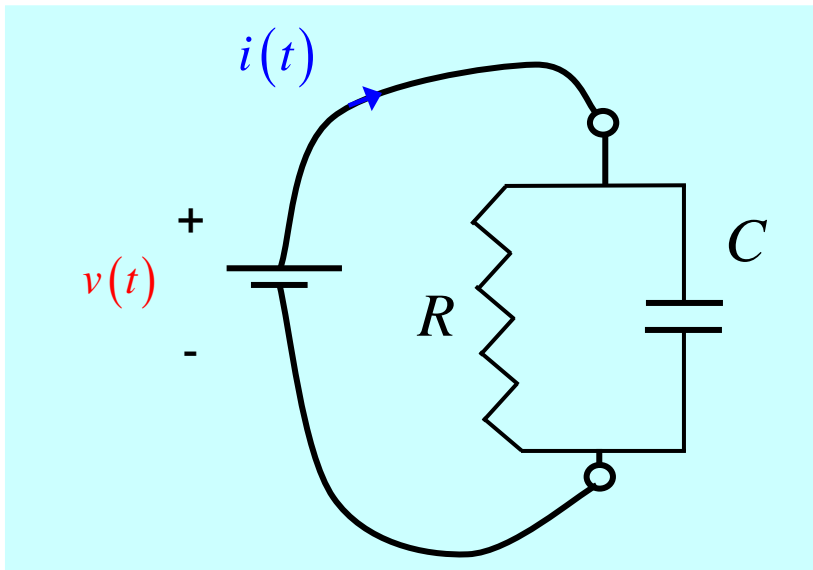
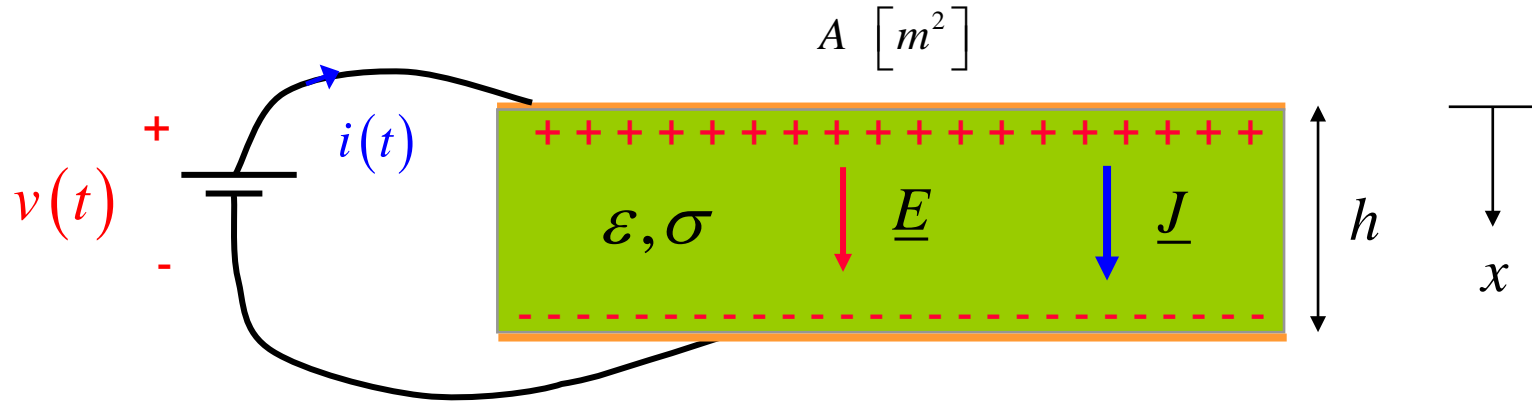
Lossy Capacitor (cont.)



$$\begin{aligned}
 i(t) &= J_x A + \frac{dQ}{dt} \\
 &= \sigma E_x A + A \frac{d\rho_s^A}{dt} \\
 &= \sigma \left(\frac{v}{h} \right) A + A \frac{dD_x}{dt} \\
 &= \frac{v}{\left(\frac{h}{\sigma A} \right)} + A\epsilon \frac{dE_x}{dt}
 \end{aligned}$$

$$\begin{aligned}
 i(t) &= \frac{v}{\left(\frac{h}{\sigma A} \right)} + A\epsilon \frac{dE_x}{dt} \\
 &= \frac{v}{R} + \left(\frac{A\epsilon}{h} \right) \frac{dv}{dt} \\
 &= \frac{v}{R} + C \frac{dv}{dt}
 \end{aligned}$$

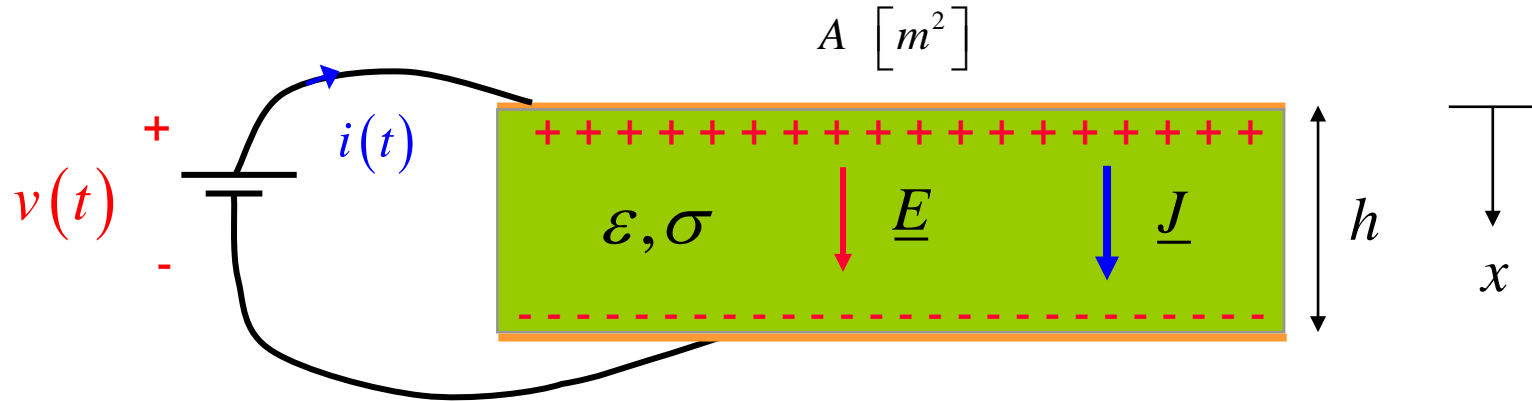
Lossy Capacitor (cont.)



$$i(t) = \frac{v(t)}{R} + C \frac{dv(t)}{dt}$$

This is the KCL equation for a resistor in parallel with a capacitor.

Lossy Capacitor (cont.)



Note on displacement current:

We can also write the current as

$$i(t) = \underbrace{J_x A}_{\text{Conduction current}} + \underbrace{\frac{dD_x}{dt} A}_{\text{Displacement current}}$$

Conduction current

Displacement current

Ampere's law:

$$\nabla \times \underline{H} = \underline{J} + \frac{\partial \underline{D}}{\partial t}$$

Conduction current
(density)

Displacement current
(density)